

Isc N-Channel MOSFET Transistor

STW20NM60FD

FEATURES

- · Low input capacitance and gate charge
- · Low gate input resistance
- 100% avalanche tested
- · Tight process control and high manufacturing yields
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



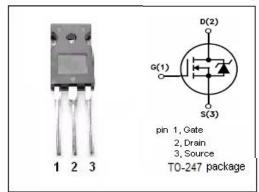
Switching application

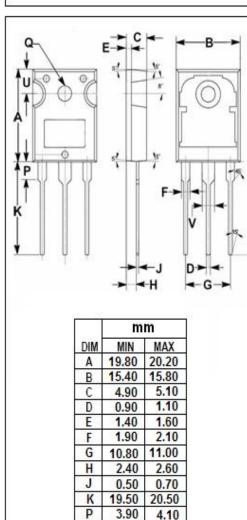


SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	600	V	
V _{GSS}	Gate-Source Voltage	±30	V	
I _D	Drain Current-Continuous@ T_c =25° \mathbb{C} T_c =100° \mathbb{C}	20 12.6	А	
I_{DM}	Drain Current-Single Pulsed	80	А	
P _D	Total Dissipation	214	W	
T _{ch}	Max. Operating Junction Temperature	-65~150	$^{\circ}$ C	
T _{stg}	Storage Temperature	-65~150	$^{\circ}$	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.59	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	30	°C/W	





Q

U

3.30

5.20

2.90

3.50

5.40

3.10



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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	600			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =±30V; I _D =0.25mA	3		5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =10A		260	290	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} = 0V			±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 600V; V _{GS} = 0V; T _J =25°C T _J =125°C			1 10	μА
V _{SDF}	Diode forward voltage	I _{SD} =20A, V _{GS} = 0 V			1.5	V

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